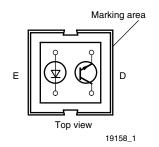


Vishay Semiconductors

Reflective Optical Sensor with Transistor Output



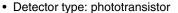


DESCRIPTION

The CNY70 is a reflective sensor that includes an infrared emitter and phototransistor in a leaded package which blocks visible light.

FEATURES

· Package type: leaded



• Dimensions (L x W x H in mm): 7 x 7 x 6

• Peak operating distance: < 0.5 mm

 Operating range within > 20 % relative collector current: 0 mm to 5 mm

• Typical output current under test: I_C = 1 mA

• Emitter wavelength: 950 nm

· Daylight blocking filter

· Lead (Pb)-free soldering released

 Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



 Optoelectronic scanning and switching devices i.e., index sensing, coded disk scanning etc. (optoelectronic encoder assemblies).

PRODUCT SUMMARY					
PART NUMBER	DISTANCE FOR MAXIMUM CTR _{rel} (1) (mm)	DISTANCE RANGE FOR RELATIVE I _{out} > 20 % (mm)	TYPICAL OUTPUT CURRENT UNDER TEST (2) (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED	
CNY70	0	0 to 5	1	Yes	

Notes

 $^{(1)}$ CTR: current transfere ratio, I_{out}/I_{in}

(2) Conditions like in table basic charactristics/sensors

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	VOLUME (1)	REMARKS		
CNY70	Tube	MOQ: 4000 pcs, 80 pcs/tube	-		

Note

(1) MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (1)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
COUPLER					
Total power dissipation	T _{amb} ≤ 25 °C	P _{tot}	200	mW	
Ambient temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	Distance to case 2 mm, t ≤ 5 s	T _{sd}	260	°C	
INPUT (EMITTER)					
Reverse voltage		V _R	5	V	
Forward current		I _F	50	mA	
Forward surge current	$t_p \le 10 \ \mu s$	I _{FSM}	3	Α	
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW	
Junction temperature		T _j	100	°C	

Document Number: 83751 Rev. 1.7, 17-Aug-09 For technical questions, contact: sensorstechsupport@vishay.com

Vishay Semiconductors

Reflective Optical Sensor with **Transistor Output**



ABSOLUTE MAXIMUM RATINGS (1)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
OUTPUT (DETECTOR)					
Collector emitter voltage		V_{CEO}	32	V	
Emitter collector voltage		V _{ECO}	7	V	
Collector current		Ic	50	mA	
Power dissipation	T _{amb} ≤ 25 °C	P _V	100	mW	
Junction temperature		T _j	100	°C	

Note

ABSOLUTE MAXIMUM RATINGS

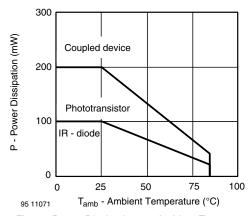


Fig. 1 - Power Dissipation vs. Ambient Temperature

BASIC CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
COUPLER						
Collector current	V _{CE} = 5 V, I _F = 20 mA, d = 0.3 mm (figure 1)	I _C ⁽²⁾	0.3	1.0		mA
Cross talk current	$V_{CE} = 5 \text{ V}, I_F = 20 \text{ mA}, \text{ (figure 2)}$	I _{CX} (3)			600	nA
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 0.1 \text{ mA},$ d = 0.3 mm (figure 1)	V _{CEsat} (2)			0.3	V
INPUT (EMITTER)						
Forward voltage	I _F = 50 mA	V _F		1.25	1.6	V
Radiant intensity	$I_F = 50 \text{ mA}, t_p = 20 \text{ ms}$	l _e			7.5	mW/sr
Peak wavelength	I _F = 100 mA	λ _P	940			nm
Virtual source diameter	Method: 63 % encircled energy	d		1.2		mm
OUTPUT (DETECTOR)						
Collector emitter voltage	I _C = 1 mA	V_{CEO}	32			V
Emitter collector voltage	I _E = 100 μA	V _{ECO}	5			V
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0 \text{ A}, E = 0 \text{ Ix}$	I _{CEO}			200	nA

Notes

- $^{(1)}$ T_{amb} = 25 °C, unless otherwise specified $^{(2)}$ Measured with the "Kodak neutral test card", white side with 90 % diffuse reflectance
- (3) Measured without reflecting medium

 $^{^{(1)}}$ $T_{amb} = 25$ °C, unless otherwise specified



Reflective Optical Sensor with Transistor Output

Vishay Semiconductors

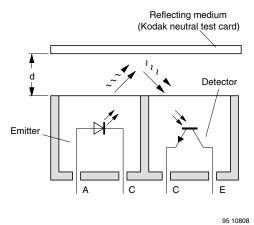


Fig. 2 - Pulse diagram

BASIC CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

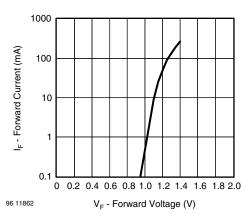


Fig. 3 - Forward Current vs. Forward Voltage

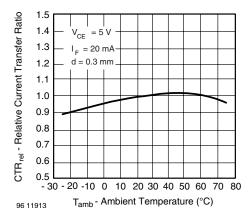


Fig. 4 - Relative Current Transfer Ratio vs. Ambient Temperature

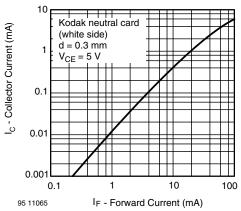


Fig. 5 - Collector Current vs. Forward Current

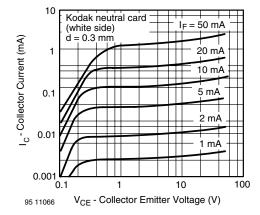


Fig. 6 - Collector Current vs. Collector Emitter Voltage

Vishay Semiconductors

Reflective Optical Sensor with Transistor Output



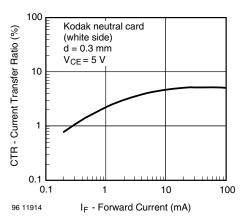


Fig. 7 - Current Transfer Ratio vs. Forward Current

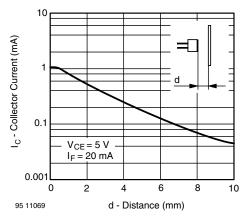


Fig. 9 - Collector Current vs. Distance

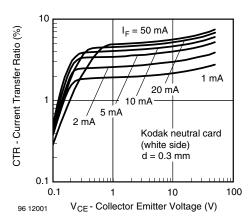


Fig. 8 - Current Transfer Ratio vs. Collector Emitter Voltage

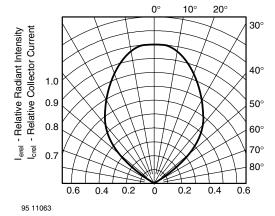


Fig. 10 - Relative Radiant Intensity/Collector Current vs.

Angular Displacement

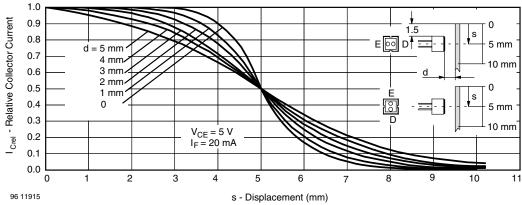


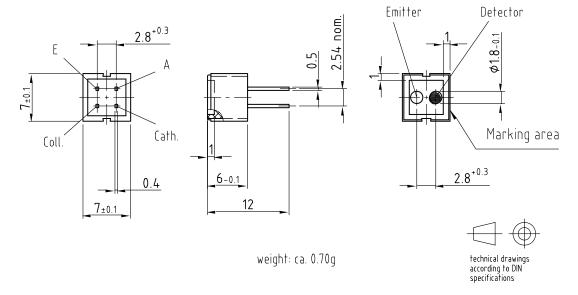
Fig. 11 - Relative Collector Current vs. Displacement



Reflective Optical Sensor with Transistor Output

Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters

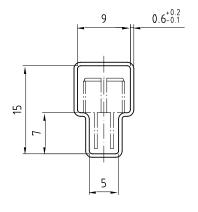


Drawing-No.: 6.544-5062.01-4

Issue: 6; 03.05.06

95 11345

TUBE DIMENSIONS in millimeters



With rubber stopper Tolerance: ±0.5mm Length: 575±1mm

Drawing-No.: 9.700-5097.01-4

Issue: 1; 25.02.00

20291

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com
Revision: 11-Mar-11 1